

PhD Dissertation Defense Announcement
Mechanical and Aerospace Engineering Department
University of Texas at Arlington

**MOLECULAR LEVEL MECHANICAL PROPERTIES OF ULTRA HIGH
TEMPERATURE CERAMICS AND THEIR NANOCOMPOSITES**

By
Md Riaz Kayser
Thesis Advisor: **Dr. Ashfaq Adnan**
1 PM, Wednesday, 22nd of July 2020
[Microsoft Teams Link](#)

Abstract

Ultra High-Temperature Ceramics (UHTC) have been of great interest in the spacecraft, aerospace, and aeronautic industry due to their high melting point and their potential application as a protective material for the stagnation areas of leading edges. In this work, the effect of nanoparticle reinforcement for achieving tailored mechanical properties of UHTC's has been studied. Two different material systems have been considered, namely the ZrB₂-based and the HfO₂-based nanocomposites. In the first study, the grain boundary driven mechanical behavior of polycrystalline ZrB₂ and ZrC-ZrB₂ nanocomposites using large-scale molecular dynamics simulations have been performed. The atomistic models of polycrystalline ZrB₂ and ZrC-ZrB₂ nanocomposite were subjected to tensile loading to determine their elastic constants and strengths. It has been found that the presence of nanoparticles imparts an insignificant effect on the mechanical properties of ZrB₂. It has also been observed that failure mechanisms of both ZrB₂ and ZrC-ZrB₂ nanocomposite are driven by grain boundary deformation. In the second study, an atomistic computational study of electric field and thermal effects on the mechanical behavior of memristor material HfO₂ have been performed. Since the material has non-symmetric crystal structure, it is observed that tensile properties along the x, y and z directions are different. In addition, the effects of electrical field on mechanical behavior are studied by varying the electrical field intensity from 0 to 0.3 v/Å gradually. For each case, atomistic snapshots are taken to identify the changes occur in the structure due to the electric field. A significant structural damage on the crystal structure of HfO₂ is observed after applying 0.3 v/Å electric field, whereas the structural change is insignificant when the magnitude of the electric field is 0.2 v/Å or less. To understand more about the damage of this material, shear loads are applied in different directions and their responses are studied in this work.